

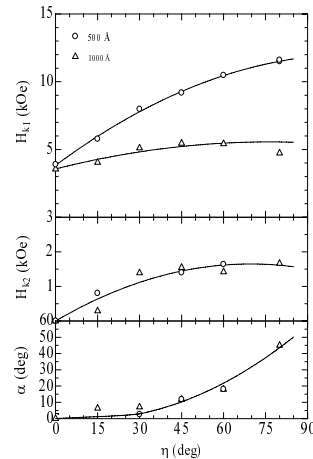
## BP04

## Magnetic Anisotropy of Obliquely Evaporated FeCo Films

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In-plane large coercive forces were obtained by oblique evaporation [1]. The evaporation technique is utilized for the production of the magnetic recording tapes. We studied the anisotropies of Co and Fe films [2,3]. To increase saturation magnetization, Fe-Co alloys are suited. We prepared magnetic films by electron-beam evaporation from an Fe<sub>30</sub>Co<sub>70</sub> source on glass substrates. Incident angle ( $\eta$ ) was changed from 0° (normal) to 90°. Film thicknesses were 500 and 1000 Å. Uniaxial tilt anisotropy field ( $H_{k1}$ ), in-plane anisotropy fields ( $H_{k2}$ ) and the tilt angle ( $\alpha$ ) were determined by ferromagnetic resonance [2,3]. In-plane magnetic anisotropies were measured by vibrating sample magnetometer (VSM). Figure 1 shows the values of  $H_{k1}$ ,  $H_{k2}$  and  $\alpha$ . To determine the three values, gyromagnetic factor ( $\gamma/2\pi$ ) was separately determined for normal incident angle films with five different thicknesses. The obtained value of  $\gamma/2\pi$  is 3.06 GHz/kOe. The large tilt anisotropy field ( $H_{k1}$ ) of 10 kOe is obtained for thickness of 500 Å films made under  $\eta=60^\circ$ . However, it decreases with film thickness. For 1000 Å film,  $H_{k1}$  is 5 kOe. Coercive forces of the films are about 400 Oe which are not so large compared to those of Co films [2]. The value of saturation magnetization ( $M_s$ ) was 1200-1300 G for the  $\eta=60^\circ$  films.

Fig. 1.  $H_{k1}$ ,  $H_{k2}$ ,  $\alpha$  versus incident angle ( $\eta$ ).

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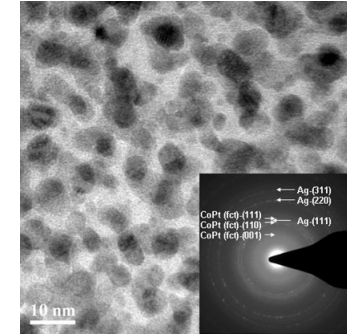
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## BP05

Nanocomposite CoPt-SiN<sub>x</sub>/Ag Films for High Density Magnetic Recording MediaG. P. Lin<sup>1\*</sup>, P. C. Kuo<sup>1</sup>, C. T. Kuo<sup>1</sup>, Y. H. Fang<sup>1</sup>, S. C. Chen<sup>2</sup>, and K. T. Huang<sup>1</sup><sup>1</sup>Institute of Materials Science and Engineering, National Taiwan University, Taipei 10617, Taiwan<sup>2</sup>Department of Materials Engineering, MingChi University of Technology, Taipei 243, Taiwan

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Recently, CoPt alloy has been investigated for ultra-high magnetic recording media application due to its high magnetic crystalline anisotropy and high thermal stability. The as-deposited CoPt film possesses a face-centered-cubic (fcc) phase which could be transferred to a face-centered-tetragonal (fct) phase by introducing a proper under layer beneath the CoPt film [1, 2]. It has been reported that the strain energy caused by the misfit between the CoPt layer and Ag provides a driving force to order the CoPt film as the Ag under layer is introduced beneath the CoPt films [3]. Moreover, the exchange coupling effect should be minimized in order to lower the media noise. Therefore, a granular microstructure of CoPt film is preferred. In this work, we studied the magnetic properties and microstructure of nanocomposite CoPt-SiN<sub>x</sub>/Ag films. It is found that when a 30 nm Ag under layer is introduced under the CoPt alloy film, the CoPt (16nm)/Ag (30 nm) films has great out-of-plane squareness ( $S_{\perp}$ ), saturation magnetization ( $M_s$ ) and out-of-plane coercivity ( $H_{c\perp}$ ) which are 0.95, 390 emu/cm<sup>3</sup> and 18 kOe, respectively. Further, the different volume percent of SiN<sub>x</sub> ceramic materials are co-sputtered with the CoPt film on the Ag under layer at room temperature to reduce the grain size of CoPt films. After deposition the films are annealed at 700°C for 30 mins. From the field emission gun high resolution transmission electron microscope (FEG-TEM) analysis, we found that the particle size of CoPt was very uniform and smaller than 10 nm as the SiN<sub>x</sub> content was increased to 55.1 vol. %.

Fig. 1. FEG-TEM images and selected area electron diffraction patterns of the (CoPt)<sub>14.9</sub>-(SiN<sub>x</sub>)<sub>55.1</sub>/Ag films which annealed at 700°C for 30 minutes.

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